

Medium Voltage Multilayer Ceramic Chip Capacitors

1. INTRODUCTION

Medium voltage multilayer ceramic chip capacitors are manufactured by using green materials without lead and cadmium. These capacitors feature series connection of multi-layer capacitor units in a MLCC to realize high voltage performance. Reliable performances are built-in through exact formulation of dielectric powders, preparation of conductive paste, advanced automatic manufacturing, and strict quality control to assure excellent control in dielectric thickness, electrode integrity, and electrode-to-termination continuity.

2. FEATURES

- a. High Voltage in a given case size.
- b. High reliability and stability.
- c. RoHS compliant.

3. APPLICATIONS

- a. DC to DC converter.
- b. High voltage coupling/DC blocking.
- c. Back-Lighting inverters.
- d. For bypassing.

4. HOW TO ORDER

COG	1206	100	J	2A	N	R
<u>DIELECTRIC</u>	<u>SIZE</u>	<u>CAPACITANCE</u>	<u>TOLERANCE</u>	<u>RATED</u>	<u>TERMINATION</u>	<u>PACKING CODE</u>
NPO=COG	0402	1PF = 1R0	A=±0.05PF	VOLTAGE	CODE	B=BULK
X7R = BX	0603	1.5PF = 1R5	B=±0.1PF	2A=100V	N=NICKEL	R=TAPED ON REEL
Y5V=Y5V	0805	2.2PF =2R2	C=±0.25PF	2D=200V	BARRIER	
	1206	100PF=101	D=±0.5PF	2E=250V		
	1210	120PF=121	F=±1%	2H=500V		
	1812	10nF=103	G=±2%	2J =630V		
	1825	100nF= 104	J=±5%			
	2220		K=±10%			
	2225		M=±20%			

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5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	Tmax (mm)	M _B min (mm)
0402 (1005)	1.00±0.05	0.50±0.05	0.55	0.15
0603 (1608)	1.60±0.10	0.80±0.10	0.95	0.20
	1.60+0.15/-0.10	0.80±0.15		
0805 (2012)	2.00±0.20	1.25±0.20	1.45	0.30
1206 (3216)	3.20±0.20	1.60±0.20	1.90	0.30
1210 (3225)	3.20±0.40	2.50±0.30	2.80	0.30
1808 (4520)	4.50±0.40	2.00±0.20	1.80	0.26
1812 (4532)	4.50±0.40	3.20±0.30	2.80	0.26
1825 (4563)	4.60±0.30	6.30±0.40	3.00	0.26
2220 (5750)	5.70±0.40	5.00±0.40	3.00	0.30
2225 (5763)	5.70±0.40	6.30±0.40	3.00	0.30

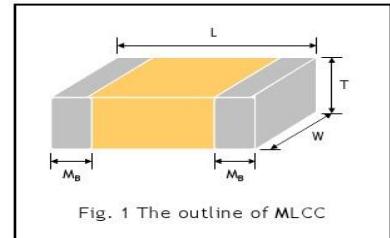


Fig. 1 The outline of MLCC

6.GENERAL ELECTRICAL DATA

Dielectric	C0G(NPO)		X7R	Y5V								
Size	0402, 0603, 0805, 1206, 1210, 1808, 1812, 1825, 2220, 2225		0603, 0805, 1206, 1210, 1808, 1812, 1825, 2220, 2225	0805, 1206, 1210, 1812								
Capacitance range*	0.5pF ~ 120nF		100pF ~ 1000nF	10nF to 820nF								
Capacitance tolerance	<table border="1"> <tr> <th>Cap. Rang</th> <th>Tolerance Spec.</th> </tr> <tr> <td>Cap≤5pF:</td> <td>B ($\pm 0.1\text{pF}$), C ($\pm 0.25\text{pF}$)</td> </tr> <tr> <td>5pF<Cap<10pF</td> <td>C ($\pm 0.25\text{pF}$), D ($\pm 0.5\text{pF}$)</td> </tr> <tr> <td>10pF≤Cap:</td> <td>F ($\pm 1\%$), G ($\pm 2\%$), J ($\pm 5\%$), K ($\pm 10\%$)</td> </tr> </table>		Cap. Rang	Tolerance Spec.	Cap≤5pF:	B ($\pm 0.1\text{pF}$), C ($\pm 0.25\text{pF}$)	5pF<Cap<10pF	C ($\pm 0.25\text{pF}$), D ($\pm 0.5\text{pF}$)	10pF≤Cap:	F ($\pm 1\%$), G ($\pm 2\%$), J ($\pm 5\%$), K ($\pm 10\%$)	J ($\pm 5\%$), K ($\pm 10\%$), M ($\pm 20\%$)	Z (-20/+80%)
Cap. Rang	Tolerance Spec.											
Cap≤5pF:	B ($\pm 0.1\text{pF}$), C ($\pm 0.25\text{pF}$)											
5pF<Cap<10pF	C ($\pm 0.25\text{pF}$), D ($\pm 0.5\text{pF}$)											
10pF≤Cap:	F ($\pm 1\%$), G ($\pm 2\%$), J ($\pm 5\%$), K ($\pm 10\%$)											
Rated voltage (WVDC)	100V, 200V, 250V, 500V, 630V		100V, 200V, 250V, 500V, 630V	100V, 200V, 250V								
Tan δ	<table border="1"> <tr> <th>Cap. Rang</th> <th>Q Spec.</th> </tr> <tr> <td>Cap<30pF:</td> <td>Q≥400+20C</td> </tr> <tr> <td>Cap≥30pF:</td> <td>Q≥1000</td> </tr> </table>		Cap. Rang	Q Spec.	Cap<30pF:	Q≥400+20C	Cap≥30pF:	Q≥1000	≤ 2.5%	≤ 5%		
Cap. Rang	Q Spec.											
Cap<30pF:	Q≥400+20C											
Cap≥30pF:	Q≥1000											
Capacitance & Tan δ Test Condition	Measured at the condition of 30~70% related humidity. for 25°C at ambient temperature		Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in ambient condition for 24±2 hours before measurement.									
Insulation resistance at Ur	≥100GΩ or R•C≥ 500Ω•F whichever is smaller		≥10GΩ or R•C≥100Ω•F whichever is smaller									
Operating temperature	-55 to +125°C		-25 to +85°C									
Capacitance characteristic	±30ppm / °C		±15%									
Termination	Cu (or Ag)/Ni/Sn (lead-free termination)		+30/-80%									

* Measured at the condition of 30~70% related humidity.

C0G(NPO): Apply $1.0 \pm 0.2\text{Vrms}$, $1.0\text{MHz} \pm 10\%$ for Cap≤1000pF and $1.0 \pm 0.2\text{Vrms}$, $1.0\text{kHz} \pm 10\%$ for Cap>1000pF, 25°C at ambient temperature

X7R: Apply $1.0 \pm 0.2\text{Vrms}$, $1.0\text{kHz} \pm 10\%$, at 25°C ambient temperature.

Y5V: Apply $1.0 \pm 0.2\text{Vrms}$, $1.0\text{kHz} \pm 10\%$, at 20°C ambient temperature.

**Measured at 500VDC for 60 sec, for $U_R > 500\text{VDC}$

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7.CAPACITANCE RANGE

7-1. C0G(NPO) Dielectric

Capacitance	DIELECTRIC	C0G(NP0)													
	SIZE	0402			0603			0805				1206			
	RATED VOLTAGE (VDC)	100	100	200	250	100	200	250	500	630	100	200	250	500	630
	0.5pF (0R5)														
	1.0pF (1R0)														
	1.2pF (1R2)														
	1.5pF (1R5)														
	1.8pF (1R8)														
	2.2pF (2R2)														
	2.7pF (2R7)														
	3.3pF (3R3)														
	3.9pF (3R9)														
	4.7pF (4R7)														
	5.6pF (5R6)														
	6.8pF (6R8)														
	8.2pF (8R2)														
	10pF (100)														
	12pF (120)														
	15pF (150)														
	18pF (180)														
	22pF (220)														
	27pF (270)														
	33pF (330)														
	39pF (390)														
	47pF (470)														
	56pF (560)														
	68pF (680)														
	82pF (820)														
	100pF (101)														
	120pF (121)														
	150pF (151)														
	180pF (181)														
	220pF (221)														
	270pF (271)														
	330pF (331)														
	390pF (391)														
	470pF (471)														
	560pF (561)														
	680pF (681)														
	820pF (821)														
	1,000pF (102)														
	1,200pF (122)														
	1,500pF (152)														
	1,800pF (182)														
	2,200pF (222)														
	2,700pF (272)														
	3,300pF (332)														
	3,900pF (392)														
	4,700pF (472)														
	5,600pF (562)														
	6,800pF (682)														
	8,200pF (822)														
	0.010μF (103)														
	0.012μF (123)														
	0.015μF (153)														
	0.018μF (183)														
	0.022μF (223)														

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7-1. C0G(NPO) Dielectric

DIELECTRIC SIZE	C0G(NPO)												
	1210				1808				1812				
RATED VOLTAGE (VDC)	100	200	250	500	630	100	200 250	500 630	100	200	250	500	630
1.0pF (1R0)													
1.2pF (1R2)													
1.5pF (1R5)													
1.8pF (1R8)													
2.2pF (2R2)													
2.7pF (2R7)													
3.3pF (3R3)													
3.9pF (3R9)													
4.7pF (4R7)													
5.6pF (5R6)													
6.8pF (6R8)													
8.2pF (8R2)													
10pF (100)													
12pF (120)													
15pF (150)													
18pF (180)													
22pF (220)													
27pF (270)													
33pF (330)													
39pF (390)													
47pF (470)													
56pF (560)													
68pF (680)													
82pF (820)													
100pF (101)													
120pF (121)													
150pF (151)													
180pF (181)													
220pF (221)													
270pF (271)													
330pF (331)													
390pF (391)													
470pF (471)													
560pF (561)													
680pF (681)													
820pF (821)													
1,000pF (102)													
1,200pF (122)													
1,500pF (152)													
1,800pF (182)													
2,200pF (222)													
2,700pF (272)													
3,300pF (332)													
3,900pF (392)													
4,700pF (472)													
5,600pF (562)													
6,800pF (682)													
8,200pF (822)													
0.010μF (103)													
0.012μF (123)													
0.015μF (153)													
0.018μF (183)													
0.022μF (223)													
0.027μF (273)													
0.033μF (333)													
0.039μF (393)													
0.047μF (473)													

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7-1. C0G(NPO) Dielectric

Capacitance	DIELECTRIC	C0G(NPO)													
	SIZE	1825				2220				2225					
	RATED VOLTAGE (VDC)	100	200	250	500	630	100	200	250	500	630	100	200	250	500
10pF (100)															
12pF (120)															
15pF (150)															
18pF (180)															
22pF (220)															
27pF (270)															
33pF (330)															
39pF (390)															
47pF (470)															
56pF (560)															
68pF (680)															
82pF (820)															
100pF (101)															
120pF (121)															
150pF (151)															
180pF (181)															
220pF (221)															
270pF (271)															
330pF (331)															
390pF (391)															
470pF (471)															
560pF (561)															
680pF (681)															
820pF (821)															
1,000pF (102)															
1,200pF (122)															
1,500pF (152)															
1,800pF (182)															
2,200pF (222)															
2,700pF (272)															
3,300pF (332)															
3,900pF (392)															
4,700pF (472)															
5,600pF (562)															
6,800pF (682)															
8,200pF (822)															
0.010μF (103)															
0.012μF (123)															
0.015μF (153)															
0.018μF (183)															
0.022μF (223)															
0.027μF (273)															
0.033μF (333)															
0.039μF (393)															
0.047μF (473)															
0.056μF (563)															
0.068μF (683)															
0.082μF (823)															
0.10μF (104)															
0.12μF (124)															

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7.2 X7R Dielectric

DIELECTRIC		X7R																
CAPACITANCE	SIZE	0603			0805				1206				1210					
		100	200	250	100	200	250	500	630	100	200	250	500	630	100	200	250	500
	100pF (101)																	
	120pF (121)																	
	150pF (151)																	
	180pF (181)																	
	220pF (221)																	
	270pF (271)																	
	330pF (331)																	
	390pF (391)																	
	470pF (471)																	
	560pF (561)																	
	680pF (681)																	
	820pF (821)																	
	1,000pF (102)																	
	1,200pF (122)																	
	1,500pF (152)																	
	1,800pF (182)																	
	2,200pF (222)																	
	2,700pF (272)																	
	3,300pF (332)																	
	3,900pF (392)																	
	4,700pF (472)																	
	5,600pF (562)																	
	6,800pF (682)																	
	8,200pF (822)																	
	0.010μF (103)																	
	0.012μF (123)																	
	0.015μF (153)																	
	0.018μF (183)																	
	0.022μF (223)																	
	0.027μF (273)																	
	0.033μF (333)																	
	0.039μF (393)																	
	0.047μF (473)																	
	0.056μF (563)																	
	0.068μF (683)																	
	0.082μF (823)																	
	0.10μF (104)																	
	0.12μF (124)																	
	0.15μF (154)																	
	0.18μF (184)																	
	0.22μF (224)																	
	0.27μF (274)																	
	0.33μF (334)																	
	0.39μF (394)																	
	0.47μF (474)																	
	0.56μF (564)																	
	0.68μF (684)																	
	0.82μF (824)																	
	1.0μF (105)																	

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7.2 X7R Dielectric

Capacitance ϵ	DIELECTRIC	X7R												
	SIZE	1808				1812				1825				
	RATED VOLTAGE (VDC)	100	200	250	500 630	100	200	250	500	630	100	200	250	500
100pF (101)														
120pF (121)														
150pF (151)														
180pF (181)														
220pF (221)														
270pF (271)														
330pF (331)														
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3,300pF (332)														
3,900pF (392)														
4,700pF (472)														
5,600pF (562)														
6,800pF (682)														
8,200pF (822)														
0.010 μ F (103)														
0.012 μ F (123)														
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0.039 μ F (393)														
0.047 μ F (473)														
0.056 μ F (563)														
0.068 μ F (683)														
0.082 μ F (823)														
0.10 μ F (104)														
0.12 μ F (124)														
0.15 μ F (154)														
0.18 μ F (184)														
0.22 μ F (224)														
0.27 μ F (274)														
0.33 μ F (334)														
0.39 μ F (394)														
0.47 μ F (474)														
0.56 μ F (564)														
0.68 μ F (684)														
0.82 μ F (824)														
1.0 μ F (105)														

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7.2 X7R Dielectric

Capacitance	DIELECTRIC	X7R								
	SIZE	2220				2225				
	RATED VOLTAGE	100	200	250	500	630	100	200	250	500
	100pF (101)									
	120pF (121)									
	150pF (151)									
	180pF (181)									
	220pF (221)									
	270pF (271)									
	330pF (331)									
	390pF (391)									
	470pF (471)									
	560pF (561)									
	680pF (681)									
	820pF (821)									
	1,000pF (102)									
	1,200pF (122)									
	1,500pF (152)									
	1,800pF (182)									
	2,200pF (222)									
	2,700pF (272)									
	3,300pF (332)									
	3,900pF (392)									
	4,700pF (472)									
	5,600pF (562)									
	6,800pF (682)									
	8,200pF (822)									
	0.010μF (103)									
	0.012μF (123)									
	0.015μF (153)									
	0.018μF (183)									
	0.022μF (223)									
	0.027μF (273)									
	0.033μF (333)									
	0.039μF (393)									
	0.047μF (473)									
	0.056μF (563)									
	0.068μF (683)									
	0.082μF (823)									
	0.10μF (104)									
	0.12μF (124)									
	0.15μF (154)									
	0.18μF (184)									
	0.22μF (224)									
	0.27μF (274)									
	0.33μF (334)									
	0.39μF (394)									
	0.47μF (474)									
	0.56μF (564)									
	0.68μF (684)									
	0.82μF (824)									
	1.0μF (105)									

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7-3. Y5V Dielectric

Capacitance	DIELECTRIC SIZE		0805			1206			Y5V			1210			1812		
	RATED VOLTAGE(VDC)		100	200	250	100	200	250	100	200	250	100	200	250	100	200	250
0.010μF (103)																	
0.015μF (153)																	
0.022μF (223)																	
0.033μF (333)																	
0.047μF (473)																	
0.068μF (683)																	
0.10μF (104)																	
0.15μF (154)																	
0.18μF (184)																	
0.22μF (224)																	
0.33μF (334)																	
0.47μF (474)																	
0.68μF (684)																	
1.0μF (105)																	

8.PACKAGE DIMENSION AND QUANTITY

Size	Thickness (mm)	Paper tape		Plastic tape	
		7" reel	13" reel	7" reel	13" reel
0402 (1005)	0.50±0.05	10k	50K	-	-
0603 (1608)	0.80±0.07	4k	15k	-	-
	0.80+0.15/-0.10	4k	15k	-	-
0805 (2012)	0.60±0.10	4k	15k	-	-
	0.80±0.10	4k	15k	-	-
	1.25±0.10	-	-	3k	10k
	1.25±0.20	-	-	3k	-
1206 (3216)	0.80±0.10	4k	15k	-	-
	0.95±0.10	-	-	3k	10k
	1.25±0.10	-	-	3k	10k
	1.60±0.20	-	-	2k	-
	1.60 +0.30/-0.10	-	-	-	-
1210 (3225)	0.95±0.10	-	-	3k	10k
	1.25±0.10	-	-	3k	10k
	1.60±0.20	-	-	2k	-
	2.00±0.20	-	-	1k	-
	2.50±0.30	-	-	1k	-
1808 (4520)	1.60±0.20	-	-	2k	-
1812 (4532)	1.25±0.10	-	-	1k	-
	1.60±0.20	-	-	1k	-
	2.00±0.20	-	-	1k	-
	2.50±0.30	-	-	0.5k	3k
1825 (4563)	1.60±0.20	-	-	1k	-
	2.00±0.20	-	-	1k	-
	2.50±0.30	-	-	0.5k	-
2220 (5750)	1.60±0.20	-	-	1k	-
	2.00±0.20	-	-	1k	-
	2.50±0.30	-	-	0.5k	-
2225 (5763)	2.00±0.20	-	-	1k	-
	2.50±0.30	-	-	0.5k	-

Unit: pieces

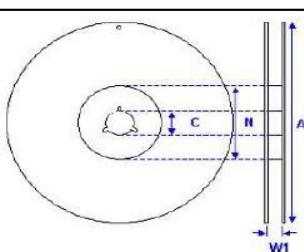


Fig. 4 The dimension of reel

Size	0402, 0603, 0805, 1206, 1210			1808,1812,1825, 2220 ,2225
	Reel size	7"	10"	13"
C	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2	13.0+0.5/-0.2
W₁	8.4+1.5/-0	8.4+1.5/-0	8.4+1.5/-0	12.4+2.0/-0
A	178.0±0.10	250.0±1.0	330.0±1.0	178.0±0.10
N	60.0±1.0/-0	100.0±1.0	100±1.0	80.0±1.0

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8-1. CARDBOARD TAPE DIMESIONS

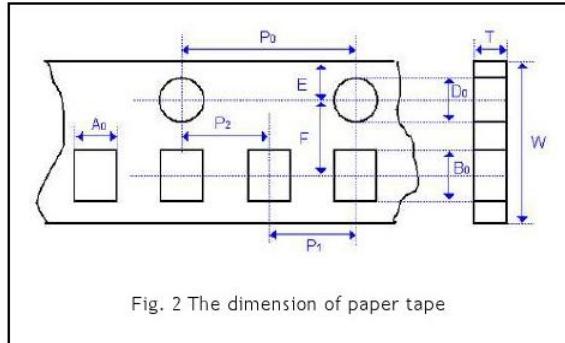


Fig. 2 The dimension of paper tape

8-2. EMBOSSED TAPE DIMENSIONS8-1.

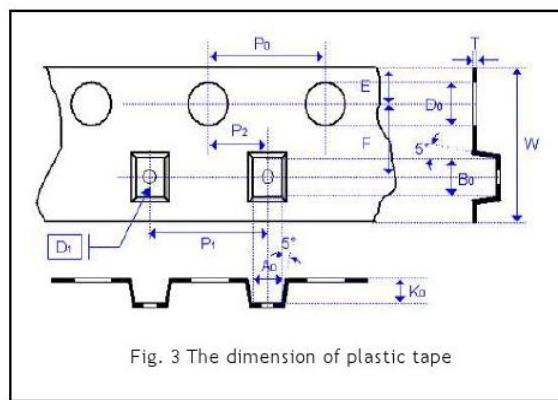


Fig. 3 The dimension of plastic tape

Size	0402	0603		0805		1206			1210	
Chip Thickness	0.50 ± 0.05	0.80 ± 0.07	$0.80 + 0.15 / -0.10$	0.80 ± 0.10	1.25 ± 0.10 1.25 ± 0.20	0.80 ± 0.10	0.95 ± 0.10 1.25 ± 0.10	1.60 ± 0.20 $1.60 + 0.30 / -0.10$	0.95 ± 0.10 1.25 ± 0.10 1.60 ± 0.20 2.00 ± 0.20	2.50 ± 0.30
A ₀	0.62 ± 0.05	$1.00 + 0.05 / -0.10$	$1.02 + 0.05 / -0.10$	1.50 ± 0.10	<1.65	2.00 ± 0.10	<2.00	<2.00	<3.05	<3.10
B ₀	1.12 ± 0.05	1.80 ± 0.10	1.80 ± 0.10	2.30 ± 0.10	<2.40	3.50 ± 0.10	<3.60	<3.70	<3.80	<4.00
T	0.60 ± 0.05	0.95 ± 0.05	0.97 ± 0.05	0.95 ± 0.05	0.23 ± 0.05	0.95 ± 0.05	0.23 ± 0.05	0.23 ± 0.05	0.23 ± 0.05	0.23 ± 0.05
K ₀	-	-	-	-	<2.50	-	<2.50	<2.50	<2.50	<3.50
W	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10
P ₀	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10
$10 \times P_0$	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20	40.00 ± 0.20
P ₁	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10
P ₂	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05
D ₀	1.55 ± 0.05	1.55 ± 0.05	1.55 ± 0.05	1.55 ± 0.05	$1.50 \pm 0.10 / -0$	1.55 ± 0.05	$1.50 \pm 0.10 / -0$	$1.50 \pm 0.10 / -0$	$1.50 \pm 0.10 / -0$	$1.50 \pm 0.10 / -0$
D ₁	-	-	-	-	1.00 ± 0.10	-	1.00 ± 0.10	1.00 ± 0.10	1.00 ± 0.10	1.00 ± 0.10
E	1.75 ± 0.05	1.75 ± 0.05	1.75 ± 0.05	1.75 ± 0.05	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10
F	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05	3.50 ± 0.05

Size	1808		1812		1825		2220		2225	
Chip Thickness	1.25 ± 0.10 1.60 ± 0.20	2.00 ± 0.20	1.25 ± 0.10 1.60 ± 0.20 2.00 ± 0.20	2.50 ± 0.30	1.60 ± 0.20 2.00 ± 0.20	2.50 ± 0.30	1.40 ± 0.15	1.60 ± 0.20 2.00 ± 0.20	2.50 ± 0.30	2.00 ± 0.20 2.50 ± 0.30
A ₀	<2.50	<2.50	<3.90	<3.90	<6.80	<6.80	<5.80	<5.80	<6.80	<6.80
B ₀	<5.30	<5.30	<5.30	<5.30	<5.30	<5.30	<6.50	<6.50	<6.50	<6.50
T	0.25 ± 0.05	0.25 ± 0.05	0.25 ± 0.05	0.25 ± 0.05	0.30 ± 0.10	0.30 ± 0.10	0.30 ± 0.10	0.30 ± 0.10	0.30 ± 0.10	0.30 ± 0.10
K ₀	<2.50	<2.50	<2.50	<3.00	<2.50	<3.10	<2.50	<3.10	<2.50	<3.10
W	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20	12.0 ± 0.20
P ₀	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	4.00 ± 0.10
$10 \times P_0$	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20	40.0 ± 0.20
P ₁	4.00 ± 0.10	4.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10	8.00 ± 0.10
P ₂	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05	2.00 ± 0.05
D ₀	$1.50 \pm 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$	$1.50 + 0.10 / -0$
D ₁	1.50 ± 0.10	1.50 ± 0.10	1.50 ± 0.10	$1.50 + / -0.10$	1.50 ± 0.10	1.50 ± 0.10	1.50 ± 0.10	1.50 ± 0.10	1.50 ± 0.10	1.50 ± 0.10
E	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10	$1.75 + / -0.1$	1.75 ± 0.1	1.75 ± 0.10	1.75 ± 0.1	1.75 ± 0.10	1.75 ± 0.10	1.75 ± 0.10
F	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.05	$5.50 + / -0.05$	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.05	5.50 ± 0.05

Medium Voltage Multilayer Ceramic Chip Capacitors

9.APPLICATION NOTES

STORAGE

To prevent the damage of solderability of terminations, the following storage conditions are recommended:

Indoors under 5 ~ 40°C and 20% ~ 70% RH.

No harmful gases containing sulfuric acid, ammonia, hydrogen sulfide or chlorine.

Packaging should not be opened until the capacitors are required for use. If opened, the pack should be re-sealed as soon as is practicable. Taped product should be stored out of direct sunlight, which might promote deterioration in tape or adhesion performance. The capacitors should be used within 6 months and checked the solderability before use.

HANDLING

Chip capacitors are dense, hard, brittle, and abrasive materials. They are liable to suffer mechanical damage, in the form of cracks or chips. Chip Capacitors should be handled with care to avoid contamination or damage. To use vacuum or plastic tweezers to pick up or plastic tweezers is recommended for manual placement. Tape and reeled packages are suitable for automatic pick and placement machine.

PREHEAT

In order to minimize the risk of thermal shock during soldering, a carefully controlled preheat is required. The rate of preheat should not exceed 4°C per second and the final preheat temperature should be within 100°C of the soldering temperature for small chips such as 0402, 0603, 0805 and 1206, within 50°C of the soldering temperature for bigger chips such as 1210, 1808, 1812, 1825, 2220 and 2225, etc.

SOLDERING

Use mildly activated rosin RA and RMA fluxes do not use activated flux. The amount of solder in each solder joint should be controlled to prevent the damage of chip capacitors caused by the stress between solder, chips, and substrate.

Hand soldering with temperature-controlled iron not exceeding 30 watts and diameter of tip less than 1.2 mm is recommended, tip of iron should not contact the ceramic body directly, and the temperature of iron should be set to not more than 260°C.

For bigger chips such as 1210, 1808, 1812, 1825, 2220 and 2225, etc. wave soldering and hand soldering are no recommended.

Refer IPC/JEDEC J-STD-020D Method recommended soldering profiles :

Reflow not sooner than 15 minutes and not longer than 4 hrs after removal from the temperature/humidity chamber, subject the sample to 3 cycle of the appropriate reflow conditions as defined as blow Table description.

Profile Feature	Pb-Free Assembly
Preheat/Soak	
Temperature Min.(T _{smin})	150°C
Temperature Max.(T _{smax})	200°C
Time(t _s) from (T _{smin} to T _{smax})	60 to 120 seconds
Ramp-up rate(T _L to T _p)	3°C /second max.
Liquidous temperature(T _L)	217°C
Time(t _L) maintained above T _L	60 to 150 seconds
Peak package body temperature(T _p)	For user T _p must not exceed the Classification temp 260°C For suppliers T _p must equal or exceed the Classification temp 260°C
Time(T _p)* within 5°C of the specified classification temperature(T _c)	30* second
Ramp-down rate (T _p to T _L)	6°C /second max.
Time 25°C to peak temperature 260°C	8 minutes max.

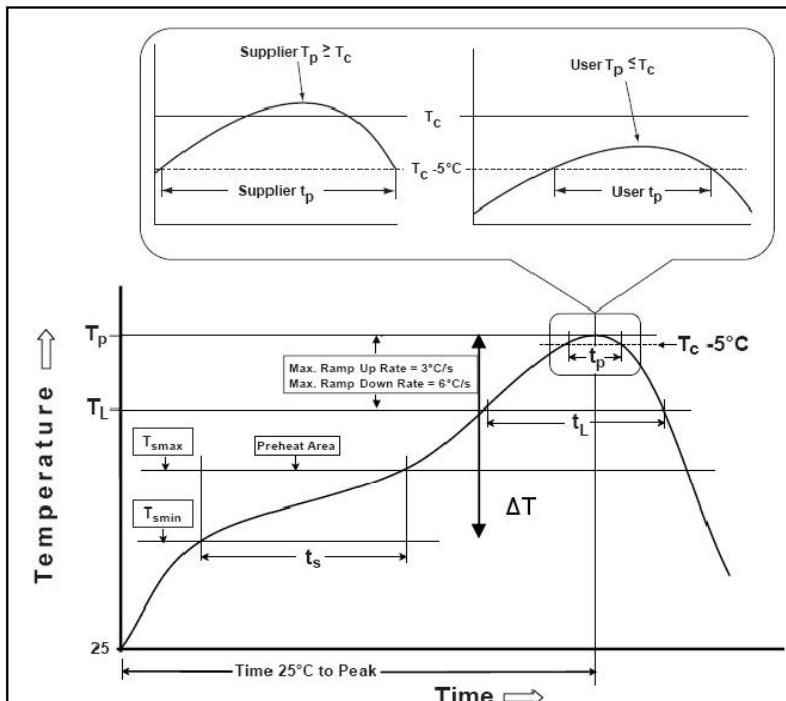
Medium Voltage Multilayer Ceramic Chip Capacitors

Lead-free : Soldering temperature = 235 to 260°C , depending on product.

Maximum temperature = Minimum temperature (235°C)+ΔT+ Tolerance for oven process and measurement(5 ~ 7°C)

Time at peak temperature = 10sec, Dwell above 217°C = 90sec, Ramping rate = 3°C/sec(heating) and 6 °C/sec(heating).

Classification Reflow Profiles



Chip Size	ΔT
0402, 0603, 0805, 1206	100 °C
1210, 1808, 1812, 1825	50 °C
2211, 2220, 2225	

Soldering	Solder Temp.(T_c)	Soldering Time (t_p)
Reflow	235 – 260 °C	< 15 sec.
Wave	230 – 260 °C	< 5 sec.

Note : For example , T_c is 260°C and time t_p is 15sec.
for user : The peak temperature must not exceed 260°C. The time above 255°C must not exceed 15 seconds.

COOLING

After soldering, cool the chips and the substrate gradually to room temperature. Natural cooling in air is recommended to minimize stress in the solder joint. A cooling rate not exceeding 4°C per second should be used when forced cooling is necessary.

CLEANING

All flux residues must be removed by using suitable electronic-grade vapor-cleaning solvents to eliminate contamination that could cause electrolytic surface corrosion. Good results can be obtained by using ultrasonic cleaning of the solvent. The choice of the proper system depends upon many factors such as component mix, flux, and solder paste and assembly method. The ability of the cleaning system to remove flux residues and contamination from under the chips is very important.

Medium Voltage Multilayer Ceramic Chip Capacitors

10.RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	Item	Test Condition	Requirements																													
1.	Visual and Dimensions	---	<ul style="list-style-type: none"> * No remarkable defect. * Dimensions to confirm to individual specification sheet. 																													
2.	Capacitance	Class I: C0G(NP0)	<ul style="list-style-type: none"> * Shall not exceed the limits given in the detailed spec. 																													
3.	Q/D.F. (Dissipation Factor)	Cap≤1000pF, 1.0±0.2Vrms, 1MHz±10% Cap>1000pF, 1.0±0.2Vrms, 1KHz±10% Class II: (X7R, Y5V) 1.0±0.2Vrms, 1kHz±10%	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Dielectric</th><th>Rated vol.(V)</th><th>Q/D.F.</th><th>Remark</th></tr> </thead> <tbody> <tr> <td>Class I(NPO)</td><td>≥ 100</td><td>Q≥1000 Q≥400+20C</td><td>Cap≥30pF Cap<30pF</td></tr> <tr> <td>Class II(X7R)</td><td>≥ 100</td><td>D.F. < 2.5%</td><td></td></tr> <tr> <td>Class II(Y5V)</td><td>≥ 100</td><td>D.F. < 5.0%</td><td></td></tr> </tbody> </table>	Dielectric	Rated vol.(V)	Q/D.F.	Remark	Class I(NPO)	≥ 100	Q≥1000 Q≥400+20C	Cap≥30pF Cap<30pF	Class II(X7R)	≥ 100	D.F. < 2.5%		Class II(Y5V)	≥ 100	D.F. < 5.0%														
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4.	Temperature Coefficient	With no electrical load.	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>T.C.</th><th>Operating Temp</th></tr> </thead> <tbody> <tr> <td>C0G(NPO)</td><td>-55~125°C at 25°C</td></tr> <tr> <td>X7R</td><td>-55~125°C at 25°C</td></tr> <tr> <td>Y5V</td><td>-25~85°C at 20°C</td></tr> </tbody> </table> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>T.C.</th><th>Capacitance Change</th></tr> </thead> <tbody> <tr> <td>C0G(NPO)</td><td>Within ±30ppm/°C</td></tr> <tr> <td>X7R</td><td>Within ±15%</td></tr> <tr> <td>Y5V</td><td>Within +30%/-80%</td></tr> </tbody> </table>	T.C.	Operating Temp	C0G(NPO)	-55~125°C at 25°C	X7R	-55~125°C at 25°C	Y5V	-25~85°C at 20°C	T.C.	Capacitance Change	C0G(NPO)	Within ±30ppm/°C	X7R	Within ±15%	Y5V	Within +30%/-80%													
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5.	Insulation Resistance	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Rated vol.(V)</th><th>Apply Voltage</th><th>Test Condition</th></tr> </thead> <tbody> <tr> <td>= 100</td><td>1 times of U_R</td><td>Max. 120 sec</td></tr> <tr> <td>>100</td><td>1 times of U_R</td><td>60 sec</td></tr> <tr> <td>> 500</td><td>500VDC</td><td>60 sec</td></tr> </tbody> </table>	Rated vol.(V)	Apply Voltage	Test Condition	= 100	1 times of U _R	Max. 120 sec	>100	1 times of U _R	60 sec	> 500	500VDC	60 sec	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Dielectric</th><th>Requirements</th></tr> </thead> <tbody> <tr> <td>Class I</td><td>≥100GΩ or Rx_C≥ 500Ω·F whichever is smaller</td></tr> <tr> <td>Class II</td><td>≥10GΩ or Rx_C≥ 100Ω·F whichever is smaller.</td></tr> </tbody> </table>	Dielectric	Requirements	Class I	≥100GΩ or Rx _C ≥ 500Ω·F whichever is smaller	Class II	≥10GΩ or Rx _C ≥ 100Ω·F whichever is smaller.											
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7.	Solderability	<ul style="list-style-type: none"> * Solder temperature: 235±5°C for (0603~1210) * Solder temperature: 245±5°C for (1808~2225) * Dipping time: 2±0.5 sec. 	75% min. coverage of all metallized area.																													
8.	Resistance to Soldering Heat	<ul style="list-style-type: none"> * Solder temperature: 260±5°C * Dipping time: 10±1 sec * Preheating: 120 to 150°C for 1 minute before immerse the capacitor in a eutectic solder. * Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 48±4 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II). 	<ul style="list-style-type: none"> * No remarkable damage. <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Dielectric</th><th>I.R</th><th>Cap Change</th><th>Q/D.F.</th></tr> </thead> <tbody> <tr> <td>Class I(NPO)</td><td>≥ 1GΩ</td><td>Within ±2.5% or ±0.25pF whichever is larger.</td><td>≤ 1.0 × Initial requirement</td></tr> <tr> <td>Class II(X7R)</td><td>≥ 1GΩ</td><td>within ±7.5%</td><td></td></tr> <tr> <td>Class II(Y5V)</td><td>≥ 1GΩ</td><td>within ±20%</td><td></td></tr> </tbody> </table> <p>* 25% max. leaching on each edge.</p>	Dielectric	I.R	Cap Change	Q/D.F.	Class I(NPO)	≥ 1GΩ	Within ±2.5% or ±0.25pF whichever is larger.	≤ 1.0 × Initial requirement	Class II(X7R)	≥ 1GΩ	within ±7.5%		Class II(Y5V)	≥ 1GΩ	within ±20%														
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9.	Temperature Cycle	<ul style="list-style-type: none"> * Conduct the five cycles according to the temperatures and time. <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Step</th><th>Temp. (°C)</th><th>Time (min.)</th></tr> </thead> <tbody> <tr> <td>1</td><td>Min. operating temp. +0/-3</td><td>30±3</td></tr> <tr> <td>2</td><td>Room temp.</td><td>2~3</td></tr> <tr> <td>3</td><td>Max. operating temp. +3/-0</td><td>30±3</td></tr> <tr> <td>4</td><td>Room temp.</td><td>2~3</td></tr> </tbody> </table> <ul style="list-style-type: none"> * Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 48±4 hrs at room temp. * Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II). 	Step	Temp. (°C)	Time (min.)	1	Min. operating temp. +0/-3	30±3	2	Room temp.	2~3	3	Max. operating temp. +3/-0	30±3	4	Room temp.	2~3	<ul style="list-style-type: none"> * No remarkable damage. <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Dielectric</th><th>I.R</th><th>Cap Change</th><th>Q/D.F.</th></tr> </thead> <tbody> <tr> <td>Class I(NPO)</td><td rowspan="3">0.25 × initial requirements.</td><td>Within ±2.5% or ±0.25pF whichever is larger.</td><td>≤ 1.0(Q) × Initial requirement</td></tr> <tr> <td>Class II(X7R)</td><td>within ±7.5%</td><td>≤ 1.5(D.F.) × Initial requirement</td></tr> <tr> <td>Class II(Y5V)</td><td>within ±20%</td><td></td></tr> </tbody> </table>	Dielectric	I.R	Cap Change	Q/D.F.	Class I(NPO)	0.25 × initial requirements.	Within ±2.5% or ±0.25pF whichever is larger.	≤ 1.0(Q) × Initial requirement	Class II(X7R)	within ±7.5%	≤ 1.5(D.F.) × Initial requirement	Class II(Y5V)	within ±20%	
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10.	Humidity (Damp Heat) Load	<ul style="list-style-type: none"> * Test temp.: 40±2°C * Humidity: 90~95%RH * Test time: 500+24/-0 hrs. * To apply voltage : rated voltage (Max. 500V) * Measurement to be made after keeping at room temp. for 24±2 hrs. (Class I) or 48±4 hrs. (Class II). 	<ul style="list-style-type: none"> * No remarkable damage. <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Dielectric</th><th>I.R</th><th>Cap Change</th><th>Q/D.F.</th></tr> </thead> <tbody> <tr> <td>Class I(NPO)</td><td rowspan="4">≥500MΩ or Rx_C≥ 25Ω·F whichever is larger.</td><td>within ±5.0% or ±2pF</td><td>Cap ≥30pF Q≥350;</td></tr> <tr> <td></td><td>whichever is larger</td><td>10pF ≤ Cap < 30pF Q≥275+2.5C</td></tr> <tr> <td>Class II(X7R)</td><td>within ±15%</td><td>Cap < 10pF Q≥200+10C</td></tr> <tr> <td>Class II(Y5V)</td><td>within ±30%</td><td>D.F. ≤ 2 × Initial requirement</td></tr> </tbody> </table>	Dielectric	I.R	Cap Change	Q/D.F.	Class I(NPO)	≥500MΩ or Rx _C ≥ 25Ω·F whichever is larger.	within ±5.0% or ±2pF	Cap ≥30pF Q≥350;		whichever is larger	10pF ≤ Cap < 30pF Q≥275+2.5C	Class II(X7R)	within ±15%	Cap < 10pF Q≥200+10C	Class II(Y5V)	within ±30%	D.F. ≤ 2 × Initial requirement												
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Medium Voltage Multilayer Ceramic Chip Capacitors

10.RELIABILITY TEST CONDITIONS AND REQUIREMENTS (Cont.)

No.	Item	Test Condition	Requirements																																																								
11.	High Temperature Load (Endurance)	<p>* Test temp.: NP0, X7R : 125±3°C Y5V: 85±3°C</p> <table border="1"> <thead> <tr> <th>Dielectric</th> <th>Rated vol.(V)</th> <th>Apply Voltage</th> </tr> </thead> <tbody> <tr> <td>NP0,</td> <td>≤ 250</td> <td>2 times of U_R</td> </tr> <tr> <td>X7R ,Y5V</td> <td>250 < V ≤ 500</td> <td>1.5 times of U_R</td> </tr> <tr> <td></td> <td>= 630</td> <td>1.2 times of U_R</td> </tr> </tbody> </table> <p>Exception item(X7R only):</p> <table border="1"> <thead> <tr> <th>Rated vol.(V)</th> <th>Size</th> <th>Cap. Range</th> <th>Apply Voltage</th> </tr> </thead> <tbody> <tr> <td rowspan="5">100</td> <td>0805</td> <td>≥ 124</td> <td rowspan="5">1.5 times of U_R</td> </tr> <tr> <td>1206</td> <td></td> </tr> <tr> <td>1210</td> <td></td> </tr> <tr> <td>1825</td> <td>≥ 105</td> </tr> <tr> <td>2220</td> <td></td> </tr> <tr> <td rowspan="4">200 & 250</td> <td>2225</td> <td></td> </tr> <tr> <td>1210</td> <td>> 224</td> </tr> <tr> <td>1812</td> <td>> 474</td> </tr> <tr> <td>1825</td> <td></td> </tr> <tr> <td rowspan="2"></td> <td>2220</td> <td>≥ 105</td> </tr> <tr> <td>2225</td> <td></td> </tr> </tbody> </table> <p>* Test time: 1000+24/-0 hrs. * Measurement to be made after keeping at room temp. for 24±2 hrs (Class I) or 48±4 hrs (Class II).</p>	Dielectric	Rated vol.(V)	Apply Voltage	NP0,	≤ 250	2 times of U_R	X7R ,Y5V	250 < V ≤ 500	1.5 times of U_R		= 630	1.2 times of U_R	Rated vol.(V)	Size	Cap. Range	Apply Voltage	100	0805	≥ 124	1.5 times of U_R	1206		1210		1825	≥ 105	2220		200 & 250	2225		1210	> 224	1812	> 474	1825			2220	≥ 105	2225		<p>* No remarkable damage.</p> <table border="1"> <thead> <tr> <th>Dielectric</th> <th>I.R</th> <th>Cap Change</th> <th>Q/D.F</th> </tr> </thead> <tbody> <tr> <td>Class I(NPO)</td> <td>≥1GΩ or $R_{xC} \geq 50\Omega \cdot F$</td> <td>within ±3.0% or ±2pF whichever is larger</td> <td rowspan="3">D.F. ≤ 2 × Initial requirement</td> </tr> <tr> <td>Class II(X7R)</td> <td></td> <td>whichever is smaller.</td> </tr> <tr> <td>Class II(Y5V)</td> <td></td> <td>within ±12.5%</td> </tr> </tbody> </table>	Dielectric	I.R	Cap Change	Q/D.F	Class I(NPO)	≥1GΩ or $R_{xC} \geq 50\Omega \cdot F$	within ±3.0% or ±2pF whichever is larger	D.F. ≤ 2 × Initial requirement	Class II(X7R)		whichever is smaller.	Class II(Y5V)		within ±12.5%
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12.	Resistance to Flexure of Substrate	<p>* The middle part of substrate shall be pressurized by means of the pressurizing rod at a rate of about 1mm per second until the deflection becomes 1mm.</p>	<p>* No remarkable damage.</p> <table border="1"> <thead> <tr> <th>Dielectric</th> <th>Cap Change</th> </tr> </thead> <tbody> <tr> <td>Class I(NPO)</td> <td>within ±3.0% or ±2pF whichever is larger</td> </tr> <tr> <td>Class II(X7R)</td> <td>within ±12.5%</td> </tr> <tr> <td>Class II(Y5V)</td> <td>within ±30%</td> </tr> </tbody> </table> <p>(This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)</p>	Dielectric	Cap Change	Class I(NPO)	within ±3.0% or ±2pF whichever is larger	Class II(X7R)	within ±12.5%	Class II(Y5V)	within ±30%																																																
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13.	Adhesive Strength of Termination	<p>* Capacitors mounted on a substrate. A force of 5N(≤0603) or 10N(> 0603) applied perpendicular to the place of substrate and parallel the line joining the center of terminations for 10±1 second.</p>	<p>* No remarkable damage or removal of the terminations.</p>																																																								
14.	Vibration Resistance	<p>* Vibration frequency: 10~55 Hz/min. * Total amplitude: 1.5mm * Test time: 6 hrs. (Two hrs each in three mutually perpendicular directions.)</p>	<p>* No remarkable damage. * Cap change and Q/D.F.: To meet initial spec.</p>																																																								